# MC 2 Emergent ferroelectrics I

Tuesday, 4 September, afternoon

**Topic: Ferroelectric Nitrides** 

Chair(s): Martina Müller/Niklas Wolff

Room:

Hours	ID	Name	Туре	Title
16h00-16h30	12973	Geoff Brennecka	Invited	Chemical Effects on Switching Pathways in Ferroelectric Wurtzites
16h30-17h00	14035	Elizabeth Dickey	Invited	Polarization and Switching in Novel Ferroelectrics: Atomic -scale Analysis via Scanning Transmission Electron Microscopy
17h00-17h15	13216	Niklas Wolff		Ex situ observation of ferroelectric domain structures in wurtzite-type AlScN thin films by TEM
17h15-17h30	14066	Niklas Kyoushi		Metal Work Function Modulation of Al1-xScxN based Memristive Devices towards  Downscaling
17h30-18h00	13104	Martina Müller	Invited	How to detect defect signatures in ferroelectric capacitors—a spectroscopic approach
18h00-18h15	13174	José P. S. Cardoso		Optical characterization of AlScN films grown by metalorganic chemical vapor deposition
18h15-18h30	13755	Maike Gremmel		Oxygen and Boron Incorporations and their Effect on Ferroelectricity in Al0.72Sc0.28N

### MC 2 Emergent ferroelectrics II

Wednesday, 4 September, morning

**Topic: Emerging properties** 

Chair(s): Athanasios Dimoulas/Jacobo Santamaria

Room:

Hours	ID	Name	Туре	Title
10h30-11h00	12820	Jacobo Santamaria	Invited	Ferroelectric twistronics with BaTiO3 membranes
11h00-11h15	13049	António Cesário		Local Probing of Structural Phase Transitions in Naturally Layered Perovskites: Li2SrNb2O7 as a case study
11h15-11h30	12851	Bruna Silva		Strain-dependent magnetic and dielectric properties of Ca3Mn2O7 thin films prepared by pulsed laser deposition

11h30-11h45	13467	Yue-Wen Fang		Ferroelectric bismuth oxides: from crystal structure prediction to device implementation
11h45-12h15	12908	Athanasios Dimoulas	Invited	Hafnia-based ferroelectric field effect memristor synapses epitaxially grown on silicon
12h15-12h30	12724	Suzanne Lancaster		Multilevel switching in ferroelectric hafnia capacitors and tunnel junctions
12h30-12h45	12917	Alexandre Baigol		From Picoseconds to Biological Timescales: Conductance Changes in Hafnia Synapses
12h45-13h00	13291	Judith Knabe		Spectroscopic insights into filamentary and ferroelectric switching in epitaxial Hf 0.5Zr0.5O2

# MC 2 Emergent ferroelectrics III

Wednesday, 4 September, afternoon

**Topic: Ferroelectric fluorites** 

Chair(s): Florencio Sanchez/Ignasi Fina

Room:

Hours	ID	Name	Туре	Title
16h00-16h30	13073	Ignasi Fina	Invited	Epitaxial ferroelectric hafnia as a suitable platform for fundamental and novel phenomena
		3		investigations
16h30-16h45	13831	Bertrand Vilguin		Deposition optimization, infrared spectroscopy and ab-initio simulations of ferroelectric
101130 101143	13031	Bertrana viiqaiii		HfZrO2 thin films
16h45-17h00	13723	Veniero Lenzi		Effect of oxygen vacancies on ferroelectric properties and phase stability of ZrO2 thin films
201113 271100	10,10	Verner o Zerizi		Effect of oxygen vacancies on terrocicculo properties and phase stability of 21 of anim minis
17h00-17h15	12878	Daniele Nazzari		Ferroelectric-enhanced Schottky-Barrier Field Effect Transistors for Logic-in-Memory
171100-171113	12070	Daniele Nazzani		applications
17h15-17h30	13392	Lucas Rhetat		A Ferroelectric-based Non-Volatile SRAM Optimized for Critical Embedded Systems
171115 171150	13332	Lucus Mictut		Trefroelectric based from Volatile 510 (10) Optimized for entical Embedded Systems
17h30-17h45	12467	Jayakrishnan Ampattu		Formalactric 7x02 thin films for high norforming near infrared photodetection
1/1150-1/1145	12407	Ravikumar		Ferroelectric ZrO2 thin films for high-performing near-infrared photodetection
17h45-18h00	12976	Pavan Nukala		Cryogenic cooling in ferroelectric hafnia proximity induced via Mott transition
18h00-18h15	13137	Alexandre Silva		Doping effect on the phase stability and ferroelectric properties in ZrO2
18h15-18h30	12956	Xiaoshan Xu		Phase diagram of doped hafnia epitaxial thin films

## MC 2 Emergent ferroelectrics IV

Thursday, 5 September, afternoon

**Topic: Emerging applications** 

Chair(s): José Silva, Maria Helena Braga

Room:

Hours	ID	Name	Туре	Title
16h00-16h30	13431	Maria Helena Braga	Invited	Electrical, thermal, and mechanical oscillators in a ferroelectric-electrolyte lead to energy
101100-101130	13431	Ivialia lielella bi aga	iliviteu	harvesting, storage, and switching
16h30-16h45	12832	Grégoire Magagnin		High energy storage antiferroelectric fluorite nanosupercapacitors
16h45-17h00	13428	Manuela C. Baptista		Advancing anode-less solid-state batteries with a ferroelectric electrolyte
17h00-17h15	13762	Dootrie Moure Comes		Revolutionizing Energy Technology: a solid-state hybrid transistor-battery architecture based
1/1100-1/1115	13/02	Beatriz Moura Gomes		on a Ferroelectric electrolyte.
17h15-17h30	12922	Ramaz Khomeriki		Photonic ferroelectric vortex lattice
17h30-17h45	13885	A.A. Bassou	Bassou	Photo-Ferroelectric Oxides for photovoltaic applications: Insights, Challenges and
171130-171143	13003			Opportunities
17h45-18h00	13387	Angelina Gudima		In-gap excitons in BiFeO 3 studied by resonant Raman spectroscopy.
18h00-18h15	12840	Tulika Maitra		Proposed two-dimensional rare-earth halide based triferroic from first principles calculations
		Alfrada Diazzuaz		
18h15-18h30	13000	Alfredo Blazquez		Spin-phonon coupling and electric field induced Raman scattering in rare-earth orthoferrites
		Martinez		

### Poster Session Thursday, 5 September

ID	Name	Title
12761	M. Das	Effect of Mn substitution on the crystal structure and magnetic properties of Sr doped
12/01	IVI. Das	bismuth ferrite
		Non-Debye type conduction mechanism in Aurivillius layered
12815		Bi4.5La0.5Fe0.9Co0.1Ti2.9Nb0.1O15 multiferroic ceramic prepared through single-step
		microwave sintering method
13060	Δ (`Miranda	Ferroelectricity vs Negative Thermal Expansion: A Nanoscopic View of Phase Transitions in
		Ruddlesden-Popper AYTiO4 (A = Na, Ag)

#### CMD31, Braga, 2 - 6 September, 2024

13757	Lloão Oliveira	Structural and Dielectric Properties of CoFe2O4/LiNbO3 Bilayer Thin Films Deposited by Laser Ablation over SrTiO3 Substrates
13794	Mael Guennou	Photostriction in a model ferroelectric studied by Laue diffraction
13886	A.A. Bassou	Photo-Ferroelectric h- LuMnO3 Thin-films